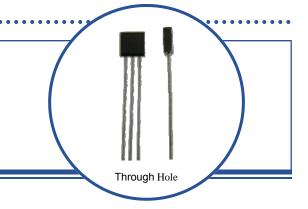
Ratiometric Linear Hall-effect Sensor OHS3150U



Features:

- · Ratiometric linear output capable of sinking and sourcing current
- 4.5 V to 6.0 V operation
- · Responds equally to positive and negative magnetic fields
- Excellent temperature stability to operate in harsh environments
- Robust package capable of withstanding harsh environments



Description:

Each ratiometric linear Hall-effect sensor contains a monolithic integrated circuit on a single chip. This circuit incorporates a quadratic Hall sensing element, which minimizes the effects of mechanical and thermal stress on the Hall element and temperature compensating circuitry to compensate for the inherent Hall element sensitivity change over temperature current.

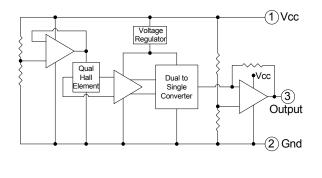
These ratiometric linear Hall-effect sensors provide an output voltage that varies in proportion to the applied magnetic field. The voltage output will increase in response to a south pole (positive) magnetic field applied perpendicular to the package symbolization face, and will decrease in response to a north pole (negative) magnetic field.

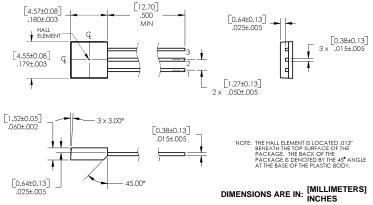
These 3150U ratiometric linear Hall-effect sensors can be used as a non-contact sensor for rotary and linear position sensing and for current sensing.

Applications:

- Non-contact magnetic sensing
- · Assembly line automation
- Machine automation
- Machine safety
- Door sensor
- Where sensing is required in dirty environments

Ordering Information						
Through Hole Temp. Range		V _{oQ} Threshold				
OHS3150U	-40°C to +125°C	V _{OQ} Change over T _A = ±50 Gauss				







Ratiometric Linear Hall-effect Sensor Emitting Diode OHS3150U



Absolute Maximum Ratings

Supply Voltage, V _{CC}	6 V
Storage Temperature Range, T _S	-65°C to +150° C
Operating Temperature Range, T _A	-40°C to +125° C
Lead Soldering Temperature (1/8 inch [3.2 mm] from case for 5 seconds with soldering iron)	260° C ⁽¹⁾
Power Dissipation, P _D	100 mW
Output Current, I _O	5 mA
Magnetic Flux Density, B	Unlimited

Electrical Characteristics (Over Operating Temperature Range at V_{CC} = 5 V, unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
V _{CC}	Supply Voltage	4.5	5.0	6.00	V	
I _{CC}	Supply Current		5.5	10.00	mA	$Vcc = 6 V$, $I_O = 0 mA$, $B = OG$
V _{OQ}	Quiescent Voltage Output	2.25	2.5	2.75	V	B = OG, T _A = 25° C
		2.10	2.5	2.90	V	B = OG, T_A = -40°C to +125°C
Io	Sink Current	0.5			mA	
Io	Source Current	-1.0			mA	

		OI				
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	
T _A	Operating Temperature Range	-40	1	125	° C	
Sens	Sensitivity @ T _A = 25° C over T _A	2.25 2.0	2.5	2.75 3.0	mV/G mV/G	
$\Delta Sens(\Delta T)$	Sens Change @ T _A > 25° C @ T _A < 25° C	-2 -10	1 1	8	% %	
$\Delta V_{OQ}(\Delta T)$	V _{OQ} Change over T _A	-	1	±35	G	
$\Delta Sens(\Delta V)$	Ratiometric Sense Change	-	100	-	%	
$\Delta V_{OQ}(\Delta V)$	Ratiometric V _{OQ} Change	-	100	-	%	
+Lin	Positive Lin ≥ 25 < 25	99 99	1 1	105 110	%	
-Lin	Negative Lin ≥ 25 < 25	95 90	-	101 101	%	
Sym	Output Symmetry	95	100	105	%	

Note:

- (1) Negative current is defined as a coming out of (sourcing) the output.
- (2) See characteristics definitions for test conditions and calculation formulas.

Ratiometric Linear Hall-effect Sensor **OHS3150U**



Characteristics Definitions

Quiescent voltage Output: With no magnetic field present the device in the guiescent state and the voltage output is approximately equal to one-half the supply voltage $(V_{00} = V_{00} / 2)$ over the operating voltage and temperature range. The change in quiescent voltage output over temperature gives the device's equivalent accuracy and is specified in gauss by the calculation.

$$\Delta V_{OQ (T)} = \frac{V_{OQ (TA)} - V_{OQ (25^{\circ}C)}}{Sens_{(25^{\circ}C)}}$$

Sensitivity: A magnetic south pole at, and perpendicular to, the device's symbolized package face will increase the voltage output above the guiescent value. Conversely a magnetic north pole will decrease the voltage output below the quiescent value. This change in voltage output with applied magnetic field is sensitivity and is specified in mV/G by the calculation.

Sens =
$$\frac{VO_{(+500G)} - V_{O_{(-500G)}}}{1000}$$

The change is sensitivity over temperature is specified in percent by the calculation

$$\Delta Sens_{(\Delta T)} = \frac{Sens_{(TA)} - Sens_{(25^{\circ}C)}}{Sens_{(25^{\circ}C)}} \times X 100\%$$

Ratiometry: The quiescent voltage output and sensitivity of these ratiometric linear Hall-effect devices are proportional to the supply voltage. The change in quiescent voltage output with supply voltage is specified in percent by the calculation

$$\Delta V_{\text{OQ }(\Delta \text{V})} = \frac{V_{\text{O }(\text{VCC})} - V_{\text{O }(5\text{V})}}{V_{\text{CC}} / 5 \text{ V}} \times 100\%$$
 This change in sensitivity with supply voltage is also specified in percent by the

calculation

$$\Delta Sens_{(\Delta V)} = \frac{V_{OQ_{(VCC)}} / V_{OQ_{(5V)}}}{V_{CC} / 5 V} X 100\%$$

Linearity & Symmetry: The ability of the voltage output to vary in constant proportion to the applied magnetic field is linearity and is specified in percent by the calculation

+ Linearity =
$$\frac{V_{O (+500G)} - V_{OQ}}{2(V_{O (250G)} - V_{OQ})}$$
 X 100%
- Linearity =
$$\frac{V_{O (-500G)} - V_{OQ}}{2(V_{O (-250G)} - V_{OQ})}$$
 X 100%

The output is also specified in percent by the calculation

itput is also specified in percent by the calculation
$$V_{O (500G)} - V_{OQ}$$
- Linearity = $V_{OQ} - V_{OQ (-500G)}$ X 100%



